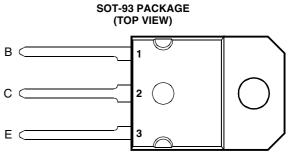
# **BOURNS®**

- Designed for Complementary Use with the BD546 Series
- 85 W at 25°C Case Temperature
- 15 A Continuous Collector Current
- Customer-Specified Selections Available



Pin 2 is in electrical contact with the mounting base.

MDTRAAA

### absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT		
	BD545		40		
Collector-base voltage (I <sub>E</sub> = 0)	BD545A	V	60	V	
Collector-base voltage (IE = 0)	BD545B	V <sub>CBO</sub>	80	V	
	BD545C		100		
	BD545		40		
Collector-emitter voltage (I <sub>B</sub> = 0) (see Note 1)	BD545A	W	60	V	
	BD545B	V <sub>CEO</sub>	80	V	
	BD545C		100		
Emitter-base voltage			5	V	
Continuous collector current			15	Α	
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			85	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)			3.5	W	
Operating free air temperature range			-65 to +150	°C	
Operating junction temperature range			-65 to +150	°C	
Storage temperature range	T <sub>stg</sub>	-65 to +150	°C		
Lead temperature 3.2 mm from case for 10 seconds	T <sub>L</sub> 260		°C		

NOTES: 1. These values apply when the base-emitter diode is open circuited.

- 2. Derate linearly to 150°C case temperature at the rate of 0.68 W/°C.
- 3. Derate linearly to 150°C  $\,$  free air temperature at the rate of 28 mW/°C.



### electrical characteristics at 25°C case temperature

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> = 30 mA (see Note 4)	I <sub>B</sub> = 0	BD545 BD545A BD545B BD545C	40 60 80 100			V
I <sub>CES</sub>	Collector-emitter cut-off current	V <sub>CE</sub> = 40 V V <sub>CE</sub> = 60 V V <sub>CE</sub> = 80 V V <sub>CE</sub> = 100 V	$V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$	BD545 BD545A BD545B BD545C			0.4 0.4 0.4 0.4	mA
I <sub>CEO</sub>	Collector cut-off current	$V_{CE} = 30 \text{ V}$ $V_{CE} = 60 \text{ V}$	$I_{B} = 0$ $I_{B} = 0$	BD545/545A BD545B/545C			0.7 0.7	mA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> = 5 V	I <sub>C</sub> = 0				1	mA
h <sub>FE</sub>	Forward current transfer ratio	$V_{CE} = 4 V$ $V_{CE} = 4 V$ $V_{CE} = 4 V$	$I_C = 1 A$ $I_C = 5 A$ $I_C = 10 A$	(see Notes 4 and 5)	60 25 10			
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	$I_B = 625 \text{ mA}$ $I_B = 2 \text{ A}$	$I_C = 5 A$ $I_C = 10 A$	(see Notes 4 and 5)			0.8 1	٧
V <sub>BE</sub>	Base-emitter voltage	V <sub>CE</sub> = 4 V	I <sub>C</sub> = 10 A	(see Notes 4 and 5)			1.8	V
h <sub>fe</sub>	Small signal forward current transfer ratio	V <sub>CE</sub> = 10 V	I <sub>C</sub> = 0.5 A	f = 1 kHz	20			
h <sub>fe</sub>	Small signal forward current transfer ratio	V <sub>CE</sub> = 10 V	I <sub>C</sub> = 0.5 A	f = 1 MHz	3	-		

NOTES: 4. These parameters must be measured using pulse techniques,  $t_p$  = 300  $\mu$ s, duty cycle  $\leq$  2%.

### thermal characteristics

PARAMETER	MIN	TYP	MAX	UNIT
R <sub>0JC</sub> Junction to case thermal resistance			1.47	°C/W
R <sub>BJA</sub> Junction to free air thermal resistance			35.7	°C/W

## resistive-load-switching characteristics at 25°C case temperature

		PARAMETER	TEST CONDITIONS †		MIN	TYP	MAX	UNIT	
Γ	t <sub>on</sub>	Turn-on time	I <sub>C</sub> = 6 A	$I_{B(on)} = 0.6 A$	$I_{B(off)} = -0.6 A$		0.6		μs
	t <sub>off</sub>	Turn-off time	$V_{BE(off)} = -4 V$	$R_1 = 5 \Omega$	$t_{\rm p} = 20 \ \mu s, \ dc \le 2\%$		1		μs

<sup>&</sup>lt;sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

<sup>5.</sup> These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

### **TYPICAL CHARACTERISTICS**

# **TYPICAL DC CURRENT GAIN** vs **COLLECTOR CURRENT** TCS633AJ 1000 $V_{CE} = 4 V$ $T_{\rm C} = 25^{\circ}{\rm C}$ $t_n = 300 \mu s$ , duty cycle < 2%h<sub>FE</sub> - DC Current Gain 100 10 0.1 10 1.0 I<sub>c</sub> - Collector Current - A

Figure 1.

**COLLECTOR-EMITTER SATURATION VOLTAGE** 

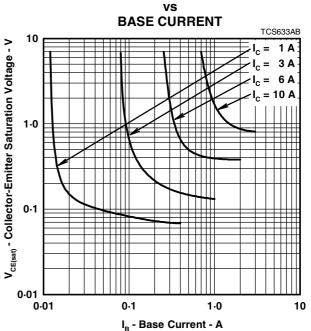
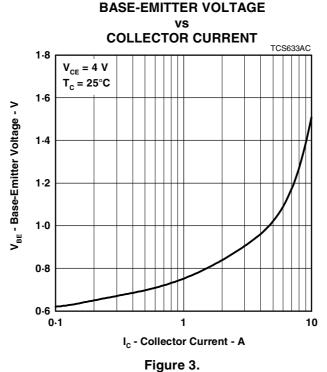


Figure 2.





#### PRODUCT INFORMATION

### **MAXIMUM SAFE OPERATING REGIONS**

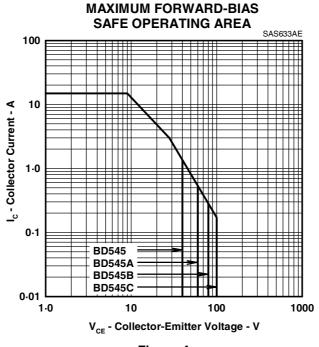


Figure 4.

### THERMAL INFORMATION

# MAXIMUM POWER DISSIPATION

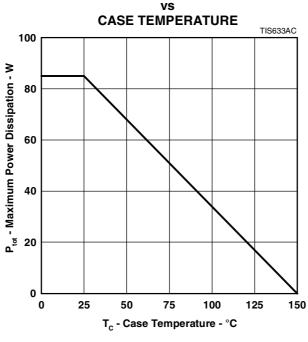


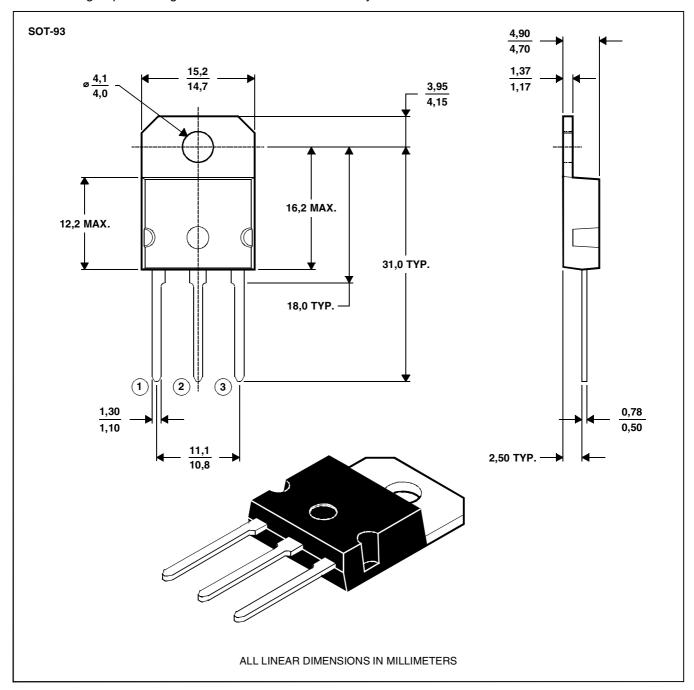
Figure 5.

### **MECHANICAL DATA**

### **SOT-93**

## 3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTE A: The centre pin is in electrical contact with the mounting tab.

**MDXXAW**